





3A SCHOTTKY BARRIER RECTIFIER POWERDI®

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Low Reverse Leakage Current
- For Use in High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- High Forward Surge Current Capability
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 [®]
- Polarity: See Diagram
- Weight: 0.093 grams (approximate)

POWERDI5



Top View



Bottom View

Note: Pins Left & Right must be electrically connected at the printed circuit board.

Ordering Information (Note 4)

Part Number	Case	Packaging
PDS360-13	POWERDI5	5000/Tape & Reel
PDS360-7	POWERDI5	1500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _R wm V _R	60	V
RMS Reverse Voltage	V _R (RMS)	42	٧
Average Rectified Output Current (See also Figure 4)	Io	3	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load	I _{FSM}	100	Α

Thermal Characteristics

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance Junction to Soldering Point	$R_{ heta}$ JS	_	3.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 5) T _A = +25°C	$R_{\theta JA}$	95	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 6) T _A = +25°C	$R_{ heta JA}$	70	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 7) T _A = +25°C	$R_{ heta JA}$	50	_	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to	+150	°C

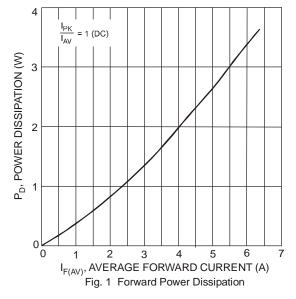
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

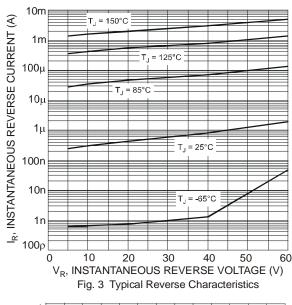
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 8)	$V_{(BR)R}$	60			>	$I_R = 0.2 \text{mA}$
			0.57	0.62		$I_F = 3A, T_J = +25^{\circ}C$
			0.53	0.60		$I_F = 3A, T_J = +100^{\circ}C$
Forward Voltage	.,		0.51	0.57	V	$I_F = 3A, T_J = +125^{\circ}C$
Forward voilage	V _F		0.70	0.76	V	I _F = 6A, T _J = +25°C
			0.62	0.70		$I_F = 6A, T_J = +100^{\circ}C$
			0.60	0.66		I _F = 6A, T _J = +125°C
			3	150	μΑ	$T_J = +25^{\circ}C, V_R = 60V$
Reverse Leakage Current (Note 8)	I_R			10	mA	$T_J = +100^{\circ}C, V_R = 60V$
		_	1.5	15	mA	$T_J = +125^{\circ}C, V_R = 60V$

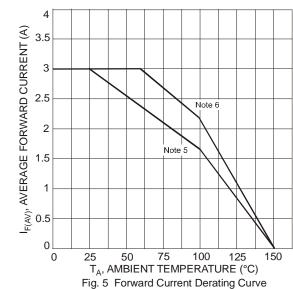
Notes:

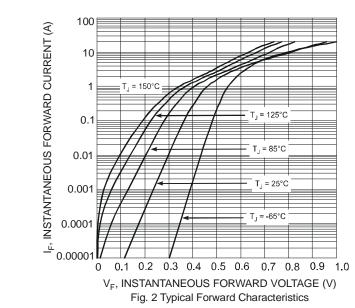
- 5. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
- 6. Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
 7. Polymide PCB, 2 oz. Copper. Cathode pad dimensions 9.4 mm x 7.4 mm. Anode pad dimensions 2.7 mm x 1.6 mm.
 8. Short duration pulse test used to minimize self-heating effect.

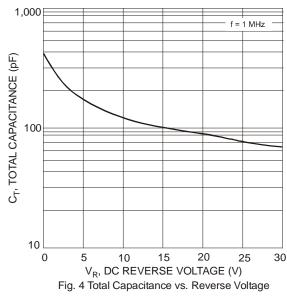


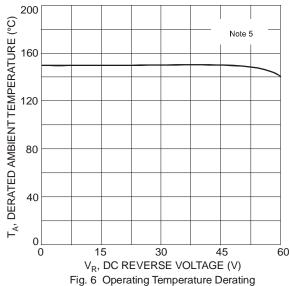








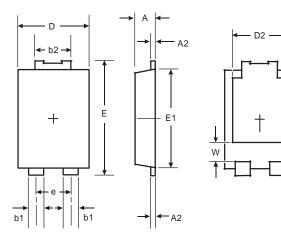






Package Outline Dimensions

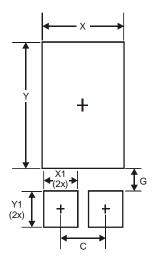
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	3.90	4.05		
D2	3.054 Typ			
Е	6.40	6.60		
е	1.84 Typ			
E1	5.30	5.45		
E2	3.549 Typ			
L	0.75	0.95		
L1	0.50	0.65		
W	1.10	1.41		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	3.360
X1	1.390
Υ	4.860
Y1	1 400



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многоканальный

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Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru_6 moschip.ru 4 moschip.ru 9